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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO		
09/576,957	05/24/2000	Atsushi Sakai	. Q54388	5486		
7	7590 08/14/2002					
Sughrue Mion Zinn Macpeak & Seas PLLC			EXAMINER			
2100 Pennsylv Washington, D	rania Avenue OC 20037-3202		TRINH, MICH	TRINH, MICHAEL MANH		
			ART UNIT	PAPER NUMBER		
			2822			
		DATE MAILED: 08/14/2002				

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	$\mu$				
	09/576,957	SAKAI ET AL.					
Office Action Summary	Examiner	Art Unit					
	Michael M Trinh	2822	<u> </u>				
The MAILING DATE of this communication Period for Reply	n appears on the cover sheet with the	correspondence a	address				
A SHORTENED STATUTORY PERIOD FOR R THE MAILING DATE OF THIS COMMUNICATI  - Extensions of time may be available under the provisions of 37 C after SIX (6) MONTHS from the mailing date of this communication  - If the period for reply specified above is less than thirty (30) days,  - If NO period for reply is specified above, the maximum statutory in  - Failure to reply within the set or extended period for reply will, by  - Any reply received by the Office later than three months after the earned patent term adjustment. See 37 CFR 1.704(b).	ON.  FR 1.136(a). In no event, however, may a reply be tion.  a reply within the statutory minimum of thirty (30) day  period will apply and will expire SIX (6) MONTHS fron  statute, cause the application to become ABANDONE	mely filed ys will be considered tim n the mailing date of this ED (35 U.S.C. § 133).	ely. communication.				
Status	20 May 2002						
1) Responsive to communication(s) filed or							
,_	This action is non-final.		tha marita ia				
3) Since this application is in condition for a closed in accordance with the practice u Disposition of Claims	allowance except for formal matters, p nder <i>Ex parte Quayle</i> , 1935 C.D. 11,	453 O.G. 213.	the ments is				
4) $\boxtimes$ Claim(s) 1-28 is/are pending in the applic	cation	:					
4a) Of the above claim(s) <u>7 and 15-28</u> is/are withdrawn from consideration.							
5) Claim(s) is/are allowed.							
6)⊠ Claim(s) <u>1-5 and 8-14</u> is/are rejected.							
7)⊠ Claim(s) <u>6</u> is/are objected to.							
8) Claim(s) are subject to restriction a	and/or election requirement.	,					
Application Papers	·						
9)☐ The specification is objected to by the Exa	miner.						
10) ☐ The drawing(s) filed on is/are: a) ☐	accepted or b) ☐ objected to by the Exa	aminer.					
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
11) ☐ The proposed drawing correction filed on is: a) ☐ approved b) ☐ disapproved by the Examiner.							
If approved, corrected drawings are required in reply to this Office action.							
12) The oath or declaration is objected to by the Examiner.							
Priority under 35 U.S.C. §§ 119 and 120							
13) Acknowledgment is made of a claim for fo	oreign priority under 35 U.S.C. § 119(	a)-(d) or (f).					
a) ☐ All b) ☐ Some * c) ☐ None of:	·						
1. Certified copies of the priority documents have been received.							
2. Certified copies of the priority documents have been received in Application No							
<ul> <li>3. Copies of the certified copies of the application from the Internation</li> <li>* See the attached detailed Office action for</li> </ul>	al Bureau (PCT Rule 17.2(a)).		al Stage				
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).							
a) ☐ The translation of the foreign languag 15)☐ Acknowledgment is made of a claim for do	• •						
Attachment(s)	-		2				
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-94 3) Information Disclosure Statement(s) (PTO-1449) Paper N	(8) 5) Notice of Informal	ry (PTO-413) Paper N Patent Application (F					

Art Unit: 2822

#### **DETAILED ACTION**

\*\*\* This office action is in response to Applicant's amendment filed on May 28, 2002.

Claims 1-28 are currently pending, in which claims 7,15-28 are non-elected without traverse.

\*\*\* The text of those sections of Title 35, U.S. Code not included in this action can be found in a prior Office action.

# Claim Rejections - 35 USC § 103

1. Claims 1-3,8-9,11,12,14 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kudoh et al (5,117,332) or Satoru (JP-05-166681) taken with Cichanowski (4,499,520).

Kudoh et al teach a method for producing a solid electrolyte capacitor comprising a metal material having thereon a dielectric film 21 having surface pores due to the valve-acting metal and a solid electrolyte formed on a desired portion of the dielectric film, the metal material having valve action (col 9, lines 16-21), wherein the method comprising the step of coating a masking material solution of pre-polymer 13 (col 9, lines 44-47; col 15, lines 44-48) so that the solution inherently infiltrates into the pores of the dielectric film 21 formed on the valve-metal substrate 12 and forms a masking layer on the infiltrated portion (Figs 4a,4b, 5), wherein the dielectric oxide film 21 may be formed over the entire surfaces of the valve metal member 10 prior of formation or attachment of the masking insulating layer 13 (col 9, lines 16-21; Fig 4a,4b). Re further claim 2, wherein due to in-situ curing of the pre-polymer solution (col 9, lines 44-47), the masking resin polymer is solidified during coating, and preventing infiltration of a solid electrolyte formed in a subsequent step. Re further claim 3, since the solid electrolyte can not infiltrate in the dielectric film where the masking resin has infiltrated, a concentration of solid electrolyte is not existed in that masked portion and thus is not higher than a detection limit value attained by using of a known electron probe microanalyser. Re further claim 8, wherein the pre-polymer solution for masking material is heat resistant resin (col 9, lines 44-47, lines 22-27; col 5, lines 39-49). Re claim 11, tantalum or aluminum for the metal is mentioned at col 18, lines 15-16. Re claims 12,14, pyrrole and thiophene, sulfonic salt for forming the solid electrolyte are mentioned at col 5, line 56 through col 6, line 6.

Kudoh et al lack to mention coating the polymer masking insulating layer 13 by press contacting.

Art Unit: 2822

However, Cichanowski teaches (at col 10, lines 1-10; Fig 1; col 9, line 55 through col 10) coating a polymer 11 onto a substrate by conventional means including brushing (press contacting), roller coating (press contacting).

It would have been obvious to one of ordinary skill in the art at the time the invention was made to form the polymer masking insulating layer 13 of Kudoh by employing conventional means including brushing (press contacting) and roller coating (press contacting) as taught by Cichanowski because of desirability and necessity to coat the polymer layer on the substrate, wherein these conventional means are alternative and effective for coating the polymer.

2. Claims 10-13 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kudoh et al (5,117,332) taken with Cichanowski (4,499,520), as applied above to claims 1-3, 8-9,11,12,14, and further of Applicant admitted prior art.

Kudoh et al teach a method for producing a solid electrolyte capacitor as applied above to claims 1-3,8-9,11,12,14.

Kudoh et al mentions tantalum or aluminum for the metal material (re claim 11) and pyrrole and thiophene, sulfonic salt for the solid electrolyte (re claim 12), but do not list other alterative materials as recited in claims 11,12-13, and do not mention mask solution contains silicon oil, silane coupling agent, or polyimidesiloxane as recited in claim 10.

Although it is considered that these alternative materials are well known in the art for substitution, Applicant admitted prior art (present specification pages 2-4, 31, line 12+, page 37, line 15+) mentions some other alternative materials as taught in the Japanese patent applications, for example, titanium, aluminum, titanium, 3,4-ethylenedioxythiophene (claim 13), silicone oil, polyimidesiloxane, etc.

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the method of Kudoh by employing these alternative materials as taught by Applicant admitted prior art and as well known in the art. This is because the substitution of art recognized equivalent materials would have been within the level of one having ordinary skill in the art.

Art Unit: 2822

3. Claims 4-5 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kudoh et al (5,117,332) and taken with Cichanowski (4,499,520), as applied above to claims 1-3, 8-9,11, 12,14, and further of Kuranuki et al (5,198,967) and Scheer (4,872,962).

The references of Kudoh and Cichanowski teach a method for producing a solid electrolyte capacitor comprising roller coating a masking solution on the surface pores of a dielectric oxide film formed on the valve-acting metal and a solid electrolyte.

The references lack to show mass production by attaching a plurality of solid electrolytic capacitors on a metal guide during roller coating.

However, Kuranuki teaches (at fig 1) to attach a plurality of solid electrolytic capacitors on a metal guide, wherein a masking film 21 is formed the entire circumference on the dielectric oxide film formed on the valve metal, wherein forming a mask layer by roller coating a making material solution is taught by Cichanowski. Scheer is cited to show the application of masking material solution to the rotated disk in forming the material solution on the entire circumference.

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to form the masking layer on the dielectric oxide film of Kudoh by employing the process of roller coating a masking material solution as combinatively taught by Cichanowski and Scheer, wherein attaching a plurality of solid electrolytic capacitors on a metal guide is taught by Kuranuki. This is because of the desirability to have mass production in forming the masking film on a circumference portion of the dielectric oxide film formed on the valve metal during roller coating process.

4. Claims 1-3,8-14 are rejected under 35 U.S.C. 103 as being anticipated by Kenichi et al (JP-05047611) taken with Applicant admitted prior art (specification pages 3-4) and as evidence with Nakamura et al (5,483,415) as evidence, and further of Robinson et al (5,795,647).

Kenichi et al teach a method for producing a solid electrolyte capacitor comprising a metal material having thereon a dielectric oxide film and a solid electrolyte formed on a desired portion of the dielectric film, the metal material having valve action (English abstract) wherein the method comprising the step of coating a masking material solution by "electrodepositing a solution containing a polyamic salt at least a part of the valve-acting metal in the area where the solid electrolyte is not formed, thereby forming a polyamic acid film and dehydration-curing the

Art Unit: 2822

film by heating to form a polyimide film", wherein the "method of forming a polyimide film by electro-deposition may successfully form a film even inside the pore parts" (see Applicant admitted prior art at specification pages 3-4) so that the solution inherently infiltrates into the dielectric oxide film formed on the valve-metal substrate and forms a masking layer on the infiltrated portion (Figs 1-3). Re further claim 2, wherein due to dehydration and curing, the masking resin polymer is solidified during coating, and preventing infiltration of a solid electrolyte formed in a subsequent step. Re further claim 3, since the solid electrolyte can not infiltrate in the dielectric film where the masking resin has infiltrated, a concentration of solid electrolyte is not existed in that masked portion and thus is not higher than a detection limit value attained by using of a known electron probe microanalyser. Re further claim 8, wherein the polyimide film as masking material is heat resistant resin. Re claim 11, aluminum for the metal is mentioned in the English abstract. Re claims 12,14, pyrrole and sulfonic salt for forming the solid electrolyte are also mentioned by Kenichi. Indeed, Nakamura et al '415 evidently teach (at figures 1-2; col 5, lines 22-42) to coat a masking material solution by immersing the valveacting tantalum metal into a liquid insulating substance so that the liquid solution infiltrates the porous chip and thus forming a masking layer on the infiltrated portion and thus preventing infiltration of a solid electrolyte formed in a subsequent step.

Kenichi et al teach to form the polymer by electrodepositing; whereas, the claims recite forming by press contacting.

However, Robinson et al teach (at col 2, lines 15-27) to form a polymer layer by employing any of several conventional means including roll coating and electrocoating.

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to form the polymer masking insulating layer of Kenichi by alternatively employing conventional means including roller coating (press contacting) or electrodepositing as taught by Robinson because of desirability and necessity to coat the polymer layer on the substrate, wherein these conventional means are alternative and effective for coating the polymer.

Regarding further claim 11, Kenichi teaches the use of aluminum for the metal material, and pyrrole and sulfonic salt for forming the solid electrolyte (re claim 12), but lacks to list other alterative materials as recited in claims 11,12, and 3,4-ethylenedioxythiophene as in claim 13,

Art Unit: 2822

and do not mention mask solution contains silicon oil, silane coupling agent, or polyimidesiloxane as in claim 10.

Although it is considered that these alternative materials are well known in the art for substitution, Applicant admitted prior art (present specification pages 2-4, 31, line 12+, page 37, line 15+) mentions some other alternative materials as taught in the Japanese patent applications, for example, titanium, aluminum, tantalum, 3,4-ethylenedioxythiophene (claim 13), silicone oil, polyimidesiloxane, etc.

Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the method of Kenichi by employing these alternative materials as taught by Applicant admitted prior art and as well known in the art. This is because the substitution of art recognized equivalent materials would have been within the level of one having ordinary skill in the art.

### Allowable Subject Matter

Claim 6 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

# Response to Amendment

- 5. Applicant's convincing remarks filed May 28, 2002 (remark pages 3-5) have overcome the rejections under 35 USC 112, first paragraph, since due to the metal material having valve action, the masking material solution infiltrate into the surface pores of the dielectric film, not through the dielectric film itself.
- 6. Applicant's remarks filed May 28, 2002 about the prior art rejections have been fully considered but they are not persuasive, and to be in moot of new ground of rejection.
- \*\*\* Applicant's remark about Kudoh et al (remark page 6) that "...since the insulating film 13 of Kudoh is formed on the conductive layer 22 (and also on valve metal member 10), and not directly on the dielectric oxide film 21, the insulating solution does not infiltrate into pores of the dielectric layer..."

Art Unit: 2822

In response, this is noted and found unconvincing since Kudoh also teaches, in another embodiment at col 9, lines 16-21, that "the dielectric oxide film may be formed over the entire surfaces of the valve member 10 prior to formation or attachment of the insulating layer 13". Accordingly, the polymer insulating solution for forming the polymer layer 13 infiltrates into pores of the dielectric oxide film 21.

- 7. Regarding coating by press contacting: The prior art references including Cichanowski (4,499,520) and Robinson et al (5,795,647) teach to coat the polymer masking insulating film by roller coating or brush which is press contacting.
- \*\*\* Any inquiry concerning this communication or earlier communications from the examiner should be directed to Michael M. Trinh whose telephone number is (703) 308-2554. The examiner can normally be reached on M-F: 8:30 Am to 5:00 Pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Whitehead Jr Carl can be reached on (703) 308-4940. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 308-7722 for regular communications and (703) 308-7724 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

Oacs

Michael Trinh Primary Examiner